
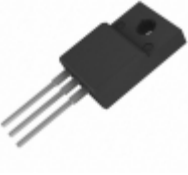

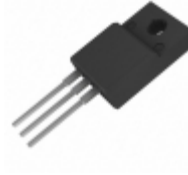

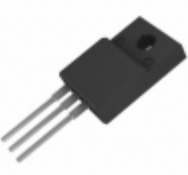



	<h2>SIHF12N60E-E3</h2>
	<p>Hersteller-Teilenummer: SIHF12N60E-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 12A TO220 FULLP</p> <p>Datenblätter:  SIHF12N60E-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 40438 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIHF12N60E-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 600V 12A TO220 FULLP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	40438 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3 Full Pack
Supplier Device-Gehäuse	TO-220 Full Pack
Verlustleistung (max)	33W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Tc)
Rds On (Max) @ Id, Vgs	380 mOhm @ 6A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	58nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	937pF @ 100V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Bulk



















































SIHF12N60E-E3 ist neu im Original, Suche SIHF12N60E-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIHF12N60E-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIHF12N60E-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIHF12N50C-E3 Vishay / Siliconix MOSFET N-CH 500V 12A TO-220</p>	 <p>SIHF12N60E-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 600V 12A TO220 FULLP</p>	 <p>SIHF12N50C-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 500V 12A TO-220</p>	 <p>SIHF12N60E-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 600V 12A TO220 FULLP</p>
 <p>SIHF12N60E-GE3 Vishay / Siliconix MOSFET N-CH 600V 12A TO220 FULLP</p>	 <p>SIHF12N60E TK12A60 Toshiba Semiconductor and Storage SIHF12N60E TK12A60 TOSHIBA</p>	 <p>SIHF12N60E Vishay Precision Group SIHF12N60E VISHAY</p>	 <p>SIHF12N60E-GE3 Vishay / Spectrol MOSFET N-CH 600V 12A TO220 FULLP</p>

heiße Teile

Mehr

 SIHB12N50E	 SIHB12N60E	 SIHF12N60E-GE3	 SIHB12N60E-GE3	 SIHF12N65E
 SIHB15N50E	 SIHB15N60E-GE3	 SIHB15N60E-GE3	 SIHB15N65E	 SIHB16N50C
 SIHB16N50CTR-E3	 SIHB18N60E	 SIHB33N60E-GE3	 SIHB33N60E-GE3	 SIHD3N50D-GE3
 SIHD3N50D-GE3	 SIHD7N60E-GE3	 SIHD7N60E-GE3	 SIHF10N40D	 SIHF10N40D-E3
 SIHF10N40D-E3	 SIHF12N50C	 SIHF12N50C-E3	 SIHF12N50C-E3	 SIHF12N60E
 SIHF12N60E-E3	 SIHF12N60E-GE3	 SIHF12N60E-GE3	 SIHF12N60E-GE3	 SIHF12N65E
 SIHF15N60E	 SIHF15N60E-E3	 SIHF15N60E-E3	 SIHF15N60E-EG3	 SIHF15N60E-GE3
 SIHF15N60E-GE3	 SIHF16N50C	 SIHF16N50C-E3	 SIHF16N50C-E3	 SIHF18N50C-E3
 SIHF18N50C-E3	 SIHF18N50D	 SIHF18N50D-E3	 SIHF18N50D-E3	 SIHF22N65E-GE3
 SIHF22N65E-GE3	 SIHF510S	 SIHF520S	 SIHF530S	 SIHF540S

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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